

/ Descriptions

Silicon PNP transistor in a TO-92 Plastic Package.

/ Features

High V_{CE0} , Complementary pair with 2SC1473.

/ Applications

General amplifier.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ hFE Classifications & Marking

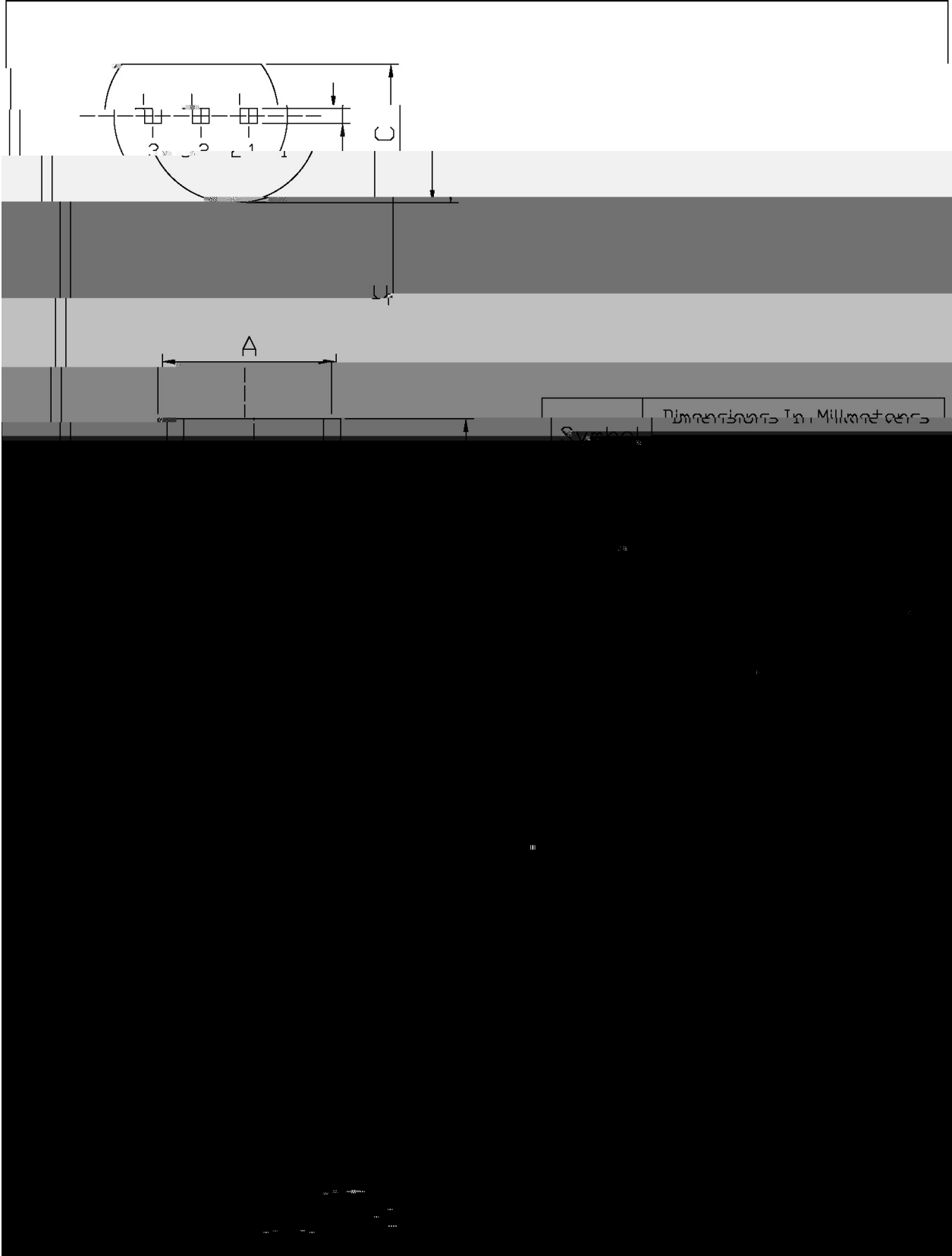
h_{FE} Classifications Symbol	P	Q	R
h_{FE} Range	30~100	60~150	100~220

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-250	V
Collector to Emitter Voltage	V_{CEO}	-200	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-70	mA
Collector Current – Continuous(Pulse)	I_{CP}	-100	mA
Collector Power Dissipation	P_C	750	mW

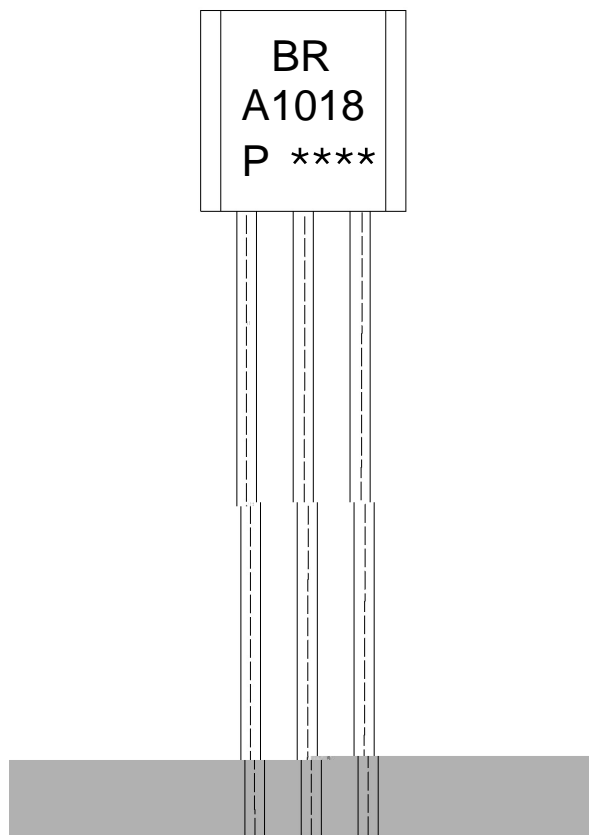
/ Package Dimensions

TO-92

Unit: mm



/ Marking Instructions



h_{FE}

Note:

BR: Company Code.

A1018: Product Type.

P: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-----|-----|----|----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255 | 5 | 5 | 0.5sec; | 2.Peak Temp.:255 5 , Duration:5 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270 ± 5 10 ± 1 sec. Temp:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units					Dimension (unit mm3)		
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box
TO-92	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195
	1,000	10	10,000	10	100,000	135×190	237×172×102	560×245×375

/ AMMO

Package Type	Units					Dimension (unit mm3)	
	Units/tape /	Tape/Inner Box /	Rows/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Inner Box	Outer Box
TO-92	3,000	1	120	10	30,000	328×230×42	480×346×235 547×407×268

/ Notices